## 1-Bit Dual-Supply Non-Inverting Level Translator

The NLSV1T244 is a 1-bit configurable dual-supply voltage level translator. The input  $A_n$  and output  $B_n$  ports are designed to track two different power supply rails,  $V_{CCA}$  and  $V_{CCB}$  respectively. Both supply rails are configurable from 0.9 V to 4.5 V allowing universal low-voltage translation from the input  $A_n$  to the output  $B_n$  port.

#### **Features**

- Wide V<sub>CCA</sub> and V<sub>CCB</sub> Operating Range: 0.9 V to 4.5 V
- High-Speed w/ Balanced Propagation Delay
- Inputs and Outputs have OVT Protection to 4.5 V
- Non-preferential V<sub>CCA</sub> and V<sub>CCB</sub> Sequencing
- Outputs at 3-State until Active V<sub>CC</sub> is Reached
- Power-Off Protection
- Outputs Switch to 3-State with V<sub>CCB</sub> at GND
- Ultra-Small Packaging: 1.2 mm x 1.0 mm UDFN6
- NLVSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

### **Typical Applications**

• Mobile Phones, PDAs, Other Portable Devices

#### **Important Information**

• ESD Protection for All Pins: HBM (Human Body Model) > 3000 V

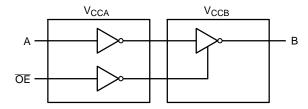


Figure 1. Logic Diagram



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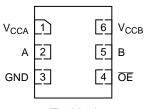
MARKING DIAGRAM



Q = Specific Device Code

M = Date Code

#### **PIN ASSIGNMENT**



(Top View)

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NLSV1T244MUTBG,	UDFN6	3000 / Tape &
NLVSV1T244MUTBG	(Pb-Free)	Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

## **PIN ASSIGNMENT**

PIN	FUNCTION
V <sub>CCA</sub>	Input Port DC Power Supply
V <sub>CCB</sub>	Output Port DC Power Supply
GND	Ground
А	Input Port
В	Output Port
ŌĒ	Output Enable

#### **TRUTH TABLE**

In	Inputs					
ŌĒ	Α	В				
L	L	L				
L	Н	Н				
Н	X	3-State				

#### **MAXIMUM RATINGS**

Symbol	Rating		Value	Condition	Unit
V <sub>CCA</sub> , V <sub>CCB</sub>	DC Supply Voltage		−0.5 to +5.5		V
V <sub>I</sub>	DC Input Voltage	Α	−0.5 to +5.5		V
V <sub>C</sub>	Control Input	ŌĒ	-0.5 to +5.5		V
Vo	DC Output Voltage (Power Down)	В	-0.5 to +5.5	$V_{CCA} = V_{CCB} = 0$	V
	(Active Mode)	В	-0.5 to +5.5		V
	(Tri–State Mode)	В	-0.5 to +5.5		V
I <sub>IK</sub>	DC Input Diode Current		-20	V <sub>I</sub> < GND	mA
I <sub>OK</sub>	DC Output Diode Current		-50	V <sub>O</sub> < GND	mA
I <sub>O</sub>	DC Output Source/Sink Current		±50		mA
I <sub>CCA</sub> , I <sub>CCB</sub>	DC Supply Current Per Supply Pin		±100		mA
I <sub>GND</sub>	DC Ground Current per Ground Pin		±100		mA
T <sub>STG</sub>	Storage Temperature		-65 to +150		°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
V <sub>CCA</sub> , V <sub>CCB</sub>	Positive DC Supply Voltage		0.9	4.5	V
VI	Bus Input Voltage		GND	4.5	V
V <sub>C</sub>	Control Input	ŌĒ	GND	4.5	V
V <sub>IO</sub>	Bus Output Voltage (Power Down Mode)	В	GND	4.5	V
	(Active Mode)	В	GND	V <sub>CCB</sub>	V
	(Tri-State Mode)	В	GND	4.5	V
T <sub>A</sub>	Operating Temperature Range		-40	+85	°C
Δt / ΔV	Input Transition Rise or Rate V <sub>I</sub> , from 30% to 70% of V <sub>CC</sub> ; V <sub>CC</sub> = 3.3 V $\pm 0.3$ V		0	10	nS

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

## DC ELECTRICAL CHARACTERISTICS

					−40°C to	+85°C	
Symbol	Parameter	Test Conditions	V <sub>CCA</sub> (V)	V <sub>CCB</sub> (V)	Min	Max	Unit
V <sub>IH</sub>	Input HIGH Voltage		3.6 – 4.5	0.9 – 4.5	2.2	_	V
	$(A, \overline{OE})$		2.7 – 3.6	1	2.0	-	
			2.3 – 2.7	1	1.6	_	1
			1.4 – 2.3		0.65 * V <sub>CCA</sub>	_	1
			0.9 – 1.4		0.9 * V <sub>CCA</sub>	_	
V <sub>IL</sub>	Input LOW Voltage		3.6 – 4.5	0.9 – 4.5	-	0.8	V
	$(A, \overline{OE})$		2.7 – 3.6		_	0.8	
			2.3 – 2.7		_	0.7	
			1.4 – 2.3		_	0.35 * V <sub>CCA</sub>	
			0.9 – 1.4		_	0.1 * V <sub>CCA</sub>	
V <sub>OH</sub>	Output HIGH Voltage	$I_{OH} = -100 \mu A; V_I = V_{IH}$	0.9 – 4.5	0.9 – 4.5	V <sub>CCB</sub> - 0.2	-	V
		$I_{OH} = -0.5 \text{ mA}; V_I = V_{IH}$	0.9	0.9	0.75 * V <sub>CCB</sub>	_	
		$I_{OH} = -2 \text{ mA}; V_I = V_{IH}$	1.4	1.4	1.05	_	
		$I_{OH} = -6 \text{ mA}; V_I = V_{IH}$	1.65	1.65	1.25	_	
			2.3	2.3	2.0	_	
		$I_{OH} = -12 \text{ mA}; V_I = V_{IH}$	2.3	2.3	1.8	_	
			2.7	2.7	2.2	-	
		$I_{OH} = -18 \text{ mA}; V_I = V_{IH}$	2.3	2.3	1.7	_	
			3.0	3.0	2.4	_	
		$I_{OH} = -24 \text{ mA}; V_I = V_{IH}$	3.0	3.0	2.2	1	
V <sub>OL</sub>	Output LOW Voltage	$I_{OL} = 100 \mu A; V_I = V_{IL}$	0.9 – 4.5	0.9 – 4.5	_	0.2	V
		$I_{OL} = 0.5 \text{ mA}; V_I = V_{IL}$	1.1	1.1	-	0.3	
		$I_{OL} = 2 \text{ mA}; V_I = V_{IL}$	1.4	1.4	-	0.35	
		$I_{OL} = 6 \text{ mA}; V_I = V_{IL}$	1.65	1.65	-	0.3	
		$I_{OL} = 12 \text{ mA}; V_I = V_{IL}$	2.3	2.3	-	0.4	
			2.7	2.7	_	0.4	
		$I_{OL} = 18 \text{ mA}; V_I = V_{IL}$	2.3	2.3	-	0.6	
			3.0	3.0	_	0.4	
		$I_{OL}$ = 24 mA; $V_I$ = $V_{IL}$	3.0	3.0	-	0.55	
l <sub>l</sub>	Input Leakage Current	$V_I = V_{CCA}$ or GND	0.9 - 4.5	0.9 – 4.5	-1.0	1.0	μΑ
l <sub>OFF</sub>	Power-Off Leakage Current	OE = 0 V	0 0.9 – 4.5	0.9 – 4.5 0	-1.0 -1.0	1.0 1.0	μΑ
I <sub>CCA</sub>	Quiescent Supply Current	$V_I = V_{CCA}$ or GND; $I_O = 0$ , $V_{CCA} = V_{CCB}$	0.9 – 4.5	0.9 – 4.5	-	1.0	μΑ
I <sub>CCB</sub>	Quiescent Supply Current	$V_I = V_{CCA}$ or GND; $I_O = 0$ , $V_{CCA} = V_{CCB}$	0.9 – 4.5	0.9 – 4.5	-	1.0	μΑ
<sub>CCA</sub> + I <sub>CCB</sub>	Quiescent Supply Current	$V_I = V_{CCA}$ or GND; $I_O = 0$ , $V_{CCA} = V_{CCB}$	0.9 – 4.5	0.9 – 4.5	-	2.0	μΑ
$\Delta I_{CCA}$	Increase in I <sub>CC</sub> per Input Voltage, Other Inputs at V <sub>CCA</sub> or GND	$V_I = V_{CCA} - 0.6 \text{ V};$ $V_I = V_{CCA} \text{ or GND}$	4.5 3.6	4.5 3.6	-	10 5.0	μΑ
$\Delta I_{CCB}$	Increase in I <sub>CC</sub> per Input Voltage, Other Inputs at V <sub>CCA</sub> or GND	$V_I = V_{CCA} - 0.6 \text{ V};$ $V_I = V_{CCA} \text{ or GND}$	4.5 3.6	4.5 3.6	-	10 5.0	μΑ
	1 00/1	1 100A 11 111					

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TOTAL STATIC POWER CONSUMPTION ( $I_{CCA} + I_{CCB}$ )

					-40°C to	o +85°C					
	V <sub>CCB</sub> (V)										
	4.	.5	3	.3	2.	.8	1	.8	0.	.9	
V <sub>CCA</sub> (V)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
4.5		2		2		2		2		< 1.5	μΑ
3.3		2		2		2		2		< 1.5	μΑ
2.8		< 2		< 1		< 1		< 0.5		< 0.5	μΑ
1.8		< 1		< 1		< 0.5		< 0.5		< 0.5	μΑ
0.9		< 0.5		< 0.5		< 0.5		< 0.5		< 0.5	μΑ

NOTE: Connect ground before applying supply voltage V<sub>CCA</sub> or V<sub>CCB</sub>. This device is designed with the feature that the power–up sequence of V<sub>CCA</sub> and V<sub>CCB</sub> will not damage the IC.

## **AC ELECTRICAL CHARACTERISTICS**

				-40°C to +85°C									
		,					V <sub>CC</sub>	<sub>B</sub> (V)					
			4	.5	3	.3	2	.8	1	.8	1.	.2	
Symbol	Parameter	V <sub>CCA</sub> (V)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
t <sub>PLH</sub> ,	Propagation	4.5		1.6		1.8		2.0		2.1		2.3	nS
t <sub>PHL</sub> (Note 1)	Delay,	3.3		1.7		1.9		2.1		2.3		2.6	
(Note 1)	A to B	2.8		1.9		2.1		2.3		2.5		2.8	
		1.8		2.1		2.4		2.5		2.7		3.0	
		1.2		2.4		2.7		2.8		3.0		3.3	
t <sub>PZH</sub> ,	Output	4.5		2.6		3.8		4.0		4.1		4.3	nS
t <sub>PZL</sub> (Note 1)	Enable,	3.3		3.7		3.9		4.1		4.3		4.6	
(Note 1)	Ō to B	2.5		3.9		4.1		4.3		4.5		4.8	
		1.8		4.1		4.4		4.5		4.7		5.0	1 '
		1.2		4.4		4.7		4.8		5.0		5.3	
t <sub>PHZ</sub> ,	Output	4.5		2.6		3.8		4.0		4.1		4.3	nS
t <sub>PLZ</sub>	Disable,	3.3		3.7		3.9		4.1		4.3		4.6	
(Note 1)	OE to B	2.5		3.9		4.1		4.3		4.5		4.8	
		1.8		4.1		4.4		4.5		4.7		5.0	
		1.2		4.4		4.7		4.8		5.0		5.3	
t <sub>OSHL</sub> ,	Output to	4.5		0.15		0.15		0.15		0.15		0.15	nS
toslh	Output Skew,	3.3		0.15		0.15		0.15		0.15		0.15	
(Note 1)	Tim	2.5		0.15		0.15		0.15		0.15		0.15	
		1.8		0.15		0.15		0.15		0.15		0.15	
		1.2		0.15		0.15		0.15		0.15		0.15	

<sup>1.</sup> Propagation delays defined per Figure 2.

#### **CAPACITANCE**

Symbol	Parameter	Test Conditions	Typ (Note 2)	Unit
C <sub>IN</sub>	Control Pin Input Capacitance	$V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CCA/B}$	3.5	pF
C <sub>I/O</sub>	I/O Pin Input Capacitance	$V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CCA/B}$	5.0	pF
C <sub>PD</sub>	Power Dissipation Capacitance	$V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CCA}, f = 10 \text{ MHz}$	5.0	pF

Typical values are at T<sub>A</sub> = +25°C.
 C<sub>PD</sub> is defined as the value of the IC's equivalent capacitance from which the operating current can be calculated from: I<sub>CC(operating)</sub> ≅ C<sub>PD</sub> x V<sub>CC</sub> x f<sub>IN</sub> where I<sub>CC</sub> = I<sub>CCA</sub> + I<sub>CCB</sub>.

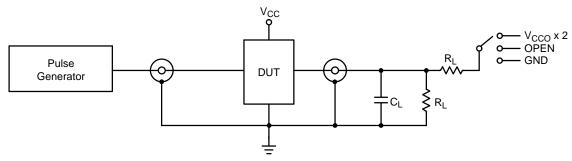


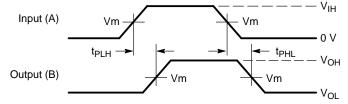
Figure 2. AC (Propagation Delay) Test Circuit

Test	Switch
t <sub>PLH</sub> , t <sub>PHL</sub>	OPEN
t <sub>PLZ</sub> , t <sub>PZL</sub>	V <sub>CCO</sub> x 2
t <sub>PHZ</sub> , t <sub>PZH</sub>	GND

C<sub>L</sub> = 15 pF or equivalent (includes probe and jig capacitance)

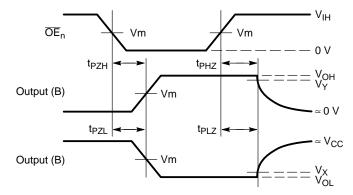
 $R_L = 2 k\Omega$  or equivalent

 $Z_{OUT}$  of pulse generator = 50  $\Omega$ 



## Waveform 1 – Propagation Delays

 $t_R = t_F = 2.0 \text{ ns}, 10\% \text{ to } 90\%; f = 1 \text{ MHz}; t_W = 500 \text{ ns}$ 



#### Waveform 2 - Output Enable and Disable Times

 $t_R = t_F = 2.0 \ \text{ns}, \ 10\% \ \text{to} \ 90\%; \ f = 1 \ \text{MHz}; \ t_W = 500 \ \text{ns}$ 

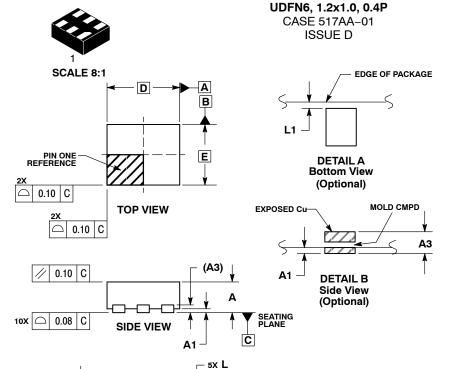
Figure 3. AC (Propagation Delay) Test Circuit Waveforms

	V <sub>CC</sub>						
Symbol	3.0 V – 4.5 V	2.3 V – 2.7 V	1.65 V – 1.95 V	1.4 V – 1.6 V	0.9 V – 1.3 V		
V <sub>mA</sub>	V <sub>CCA</sub> /2						
V <sub>mB</sub>	V <sub>CCB</sub> /2						
V <sub>X</sub>	V <sub>OL</sub> x 0.1						
$V_{Y}$	V <sub>OH</sub> x 0.9						

6X b

0.10 С A B

0.05 С NOTE 3



е

**BOTTOM VIEW** 

**DATE 03 SEP 2010** 

#### NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 mm FROM TERMINAL.

  COPLANARITY APPLIES TO THE EXPOSED
- PAD AS WELL AS THE TERMINALS.

	MILLIMETERS							
DIM	MIN	MAX						
Α	0.45	0.55						
A1	0.00	0.05						
А3	0.127	REF						
b	0.15	0.25						
D	1.20	BSC						
Е	1.00	BSC						
е	0.40	BSC						
Ĺ	0.30	0.40						
L1	0.00	0.15						
12	0.40	0.50						

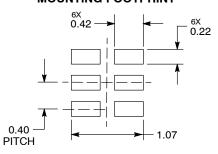
#### **GENERIC** MARKING DIAGRAM\*



= Specific Device Code = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

## **MOUNTING FOOTPRINT\***



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DESCRIPTION:	6 PIN UDFN, 1.2X1.0, 0.4P		PAGE 1 OF 1

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